TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP3021(S),TLP3022(S),TLP3023(S)

OFFICE MACHINE
HOUSEHOLD USE EQUIPMENT
TRIAC DRIVER
SOLID STATE RELAY

The TOSHIBA TLP3021 (S), TLP3022 (S) and TLP3023 (S) consist of photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP.

• Peak Off-State Voltage : 400 V (min)

• Trigger LED Current : 15 mA (max) (TLP3021(S))

10 mA (max) (TLP3022(S))

5 mA (max) (TLP3023(S))

On-State Current : 100 mA (max)
 Isolation Voltage : 5000Vrms(Min)

UL Recognized : UL1577, File No. E67349

SEMKO Approved : SS EN60065

SS EN60950, File No.9841105

• BSI Approved : BS EN60065, File No.8385

BS EN60950, File No.8386

• Option (D4) type

VDE approved: DIN EN60747-5-2(

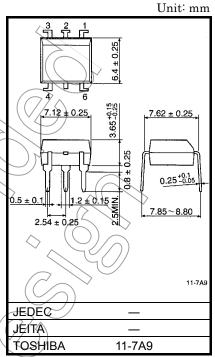
Approved No. 40009302

Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

(Note):When a EN60747-5-2 approved type is needed please designate the "Option (D4)"

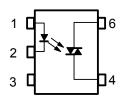
Construction Mechanical Rating

	7.62 mm pich Standard Type	10.16 mm pich TLPxxxxF Type
Creepage Distance	7.0 mm (Min)	8.0 mm (Min)
Clearance	7.0 mm (Min)	8.0 mm (Min)
Insulation Thickness	0.5 mm (Min)	0.5 mm (Min)



Weight: 0.39g (typ.)

Pin Configuration (top view)



- 1: Anode
- 2: Csthode
- 3: N.C.
- 4:Terminal 1
- 6:Terminal 2



Absolute Maximum Ratings (Ta=25°C)

	CHARACTERISTIC		SYMBOL	RATING	UNIT
	Forward Current	l _F	50	mA	
	Forward Current Derating (Ta≥53°C)	ΔI _F /°C	-0.7	mA /°C	
LED	Peak Forward Current (100µs pulse, 100pps)	IFP	<1.	Α	
	Power Dissipation			100	mW
	Power Dissipation Derating (Ta≥25°C)		ΔP _D /°C	-1(0	mW/°C
	Reverse Voltage		V _R	5	/ v
	Junction Temperature			(/125))	°C
	Off-State Output Terminal Voltage	V _{DRM}	400	V	
	0.011.0000	Ta=25°C	. ((100	
	On-State RMS Current	Ta=70°C	I _{I(RMS)} 50		mA
-oR	On-State Current Derating (Ta≥25°C)	ΔIτ/°C	-1.1	mA /°C	
DETECTOR	Peak On-State Current (100µs pulse, 120pps)	ΛŢΡ	2	A	
DEJ	Peak Nonrepetitive Surge Current (Pw=10ms)	Utsm .	1.2		
	Power Dissipation	> P _D	300	mW	
	Power Dissipation Derating (Ta≥25°C)	ΔP _D /°C	(-4.0	mW/°C	
	Junction Temperature	T _j	115	°C	
Stor	rage Temperature Range		T _{stg}	-55 to 150	°C
Ope	erating Temperature Range	Topt	-40 to 100	°C	
Lea	d Soldering Temperature (10s)	T _{sol}	260	°C	
Tota	al Package Power Dissipation	PT	330	mW	
Tota	al Package Power Dissipation Derating (₹a≥25°6)	ΔP _T /°C	-4.4	mW /°C	
Isola	ation Voltage (AC,1min. , R.H.≤60%)	BVS	5000	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions" "Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 2) Device considered a two terminal device :Pins1,2 and 3 shorted together and pin4 and pin6 shorted together.

Recommended Operating Conditions

	$\overline{}$				
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V _{AC}	1		120	V_{ac}
Forward Current	I _F *	15	20	25	mA
Peak On-State Current	I _{TP}			1	Α
Operating Temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

^{*}In The case of TLP3022



Individual Electrical Characteristics (Ta=25°C)

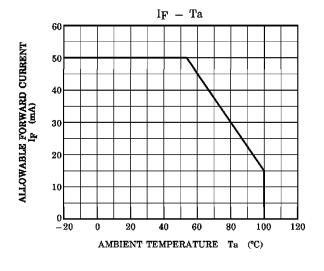
CHARACTERISTIC SYMBOL		TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
	Forward Voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	V _R = 5 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f=1MHz	-<	10	_	pF
2	Peak Off-State Current	I _{DRM}	V _{DRM} =400V	_	10	1000	nA
0 _	Peak On-State Voltage	V_{TM}	I _{TM} =100mA	_	1.7	3.0	V
O	Holding Current	lΗ	_	6	0.6	_	mA
DETE	Critical Rate of Rise of Off-State Voltage	dv/dt	Vin=120Vrms , Ta=85°C (Fig.1)	200	500	_	V/µs
	Critical Rate of Rise of Commutating Voltage	dv/dt(c)	Vin=30Vrms , IT=15mA (Fig.1)	72	0.2	_	V/µs

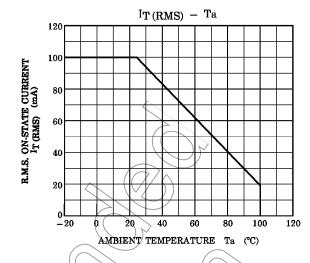
Coupled Electrical Characteristics (Ta=25°C)

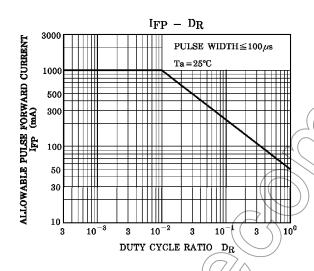
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	TLP3021(S)			_ `	(L)	(15)/	
Trigger LED Current	TLP3022(S)	I _{FT}	V _T =3V	-(5) 10	mA
	TLP3023(S)		4()	_(_	\rightarrow	5	
Capacitance (Input to C	Output)	Cs	VS=0, f=1MHz	$\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{\overline{$	0.8	0.8 — pF	
Isolation Resistance		Rs	VS=500V(R.H.≤60%)	5×10 ¹⁰	10 ¹⁴	_	Ω
		<	AC , 1minute	5000	_	_	Vrms
Isolation Voltage		BVs	AC , 1second,in oil))—	10000	_	VIIIIS
			DC , 1minute,in oil	//-	10000	_	Vdc

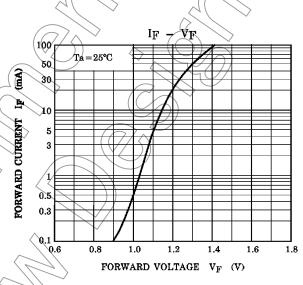
Fig. 1 dv / dt test circuit

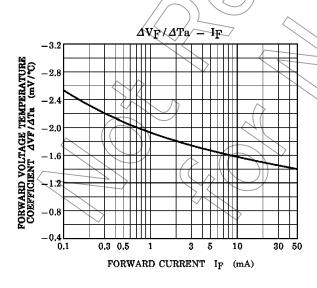
VCC 1200 2 3 4 2 2 K0 dv / dt (c) dv / dt

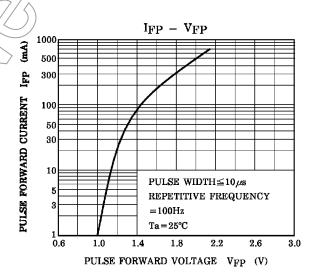






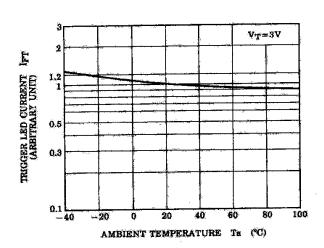




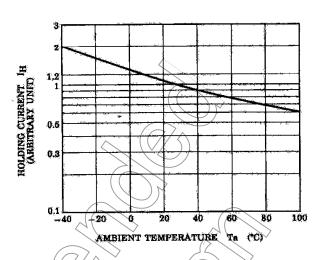


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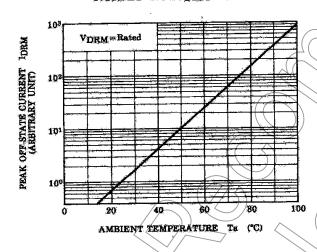
NORMALIZED IFT - Ta



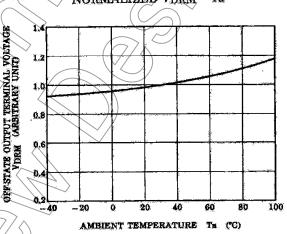
NORMALIZED IH - Ta



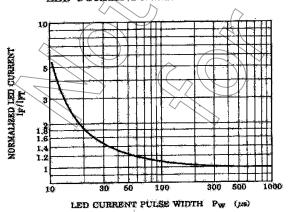
NORMALIZED IDRM - Ta



NORMALIZED VDRM -



NORMALIZED LED CURRENT - LED CURRENT PULSE WIDTH



5



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